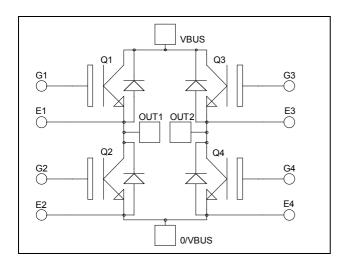


Full - Bridge NPT IGBT Power Module





O/VBUS

Application

- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

Features

- Non Punch Through (NPT) FAST IGBT
 - Low voltage drop
 - Low tail current
 - Switching frequency up to 50 kHz
 - Soft recovery parallel diodes
 - Low diode VF
 - Low leakage current
 - RBSOA and SCSOA rated
- Kelvin emitter for easy drive
- Very low stray inductance
 - Symmetrical design
 - M5 power connectors
- High level of integration



- Outstanding performance at high frequency operation
- Stable temperature behavior
- Very rugged
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Easy paralleling due to positive TC of VCEsat
- Low profile
- RoHS compliant

Absolute maximum ratings

Symbol	Parameter		Max ratings	Unit
V_{CES}	Collector - Emitter Breakdown Voltage		1200	V
т	Continuous Collector Current	$T_c = 25^{\circ}C$	200	
I_{C}	Continuous Conector Current	$T_c = 80^{\circ}C$	150	A
I_{CM}	Pulsed Collector Current	$T_c = 25^{\circ}C$	300	
V_{GE}	Gate – Emitter Voltage		±20	V
P_{D}	Maximum Power Dissipation	$T_c = 25^{\circ}C$	961	W
RBSOA	Reverse Bias Safe Operating Area	$T_j = 150^{\circ}C$	300A @ 1200V	

TAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



All ratings @ $T_j = 25$ °C unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
Ţ	Zero Gate Voltage Collector Current	$V_{GE} = 0V$	$T_j = 25$ °C			350	۸
I_{CES}	Zero Gate Voltage Collector Current	$V_{CE} = 1200V$	$T_j = 125$ °C			600	μΑ
V	Collector Emitter seturation Voltage	$V_{GE} = 15V$	$T_j = 25$ °C		3.2	3.7	V
$V_{CE(sat)}$	Collector Emitter saturation Voltage	$I_C = 150A$ $T_j =$	$T_j = 125$ °C		3.9		v
$V_{GE(th)}$	Gate Threshold Voltage	$V_{GE} = V_{CE}$, $I_C = 5 \text{ mA}$		4.5		6.5	V
I_{GES}	Gate – Emitter Leakage Current	$V_{GE} = \pm 20V, V_{CE} = 0V$				±500	nA

Dynamic Characteristics

•	Characteristic	Test Conditions	Min	Тур	Max	Unit
Cies	Input Capacitance	$V_{GE} = 0V$		10.2		
C_{oes}	Output Capacitance	$V_{CE} = 25V$		1.4		nF
C_{res}	Reverse Transfer Capacitance	f = 1MHz		0.75		
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (25°C)		120		
T_{r}	Rise Time	$V_{GE} = 15V$		50		nc
$T_{d(off)}$	Turn-off Delay Time	$V_{Bus} = 600V$ $I_C = 150A$		310		ns
T_{f}	Fall Time	$R_G = 5.6\Omega$		20		
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (125°C)		130		
T_{r}	Rise Time	$V_{GE} = 15V$		60		
$T_{d(off)}$	Turn-off Delay Time	$V_{Bus} = 600V$ $I_{C} = 150A$		360		ns
T_{f}	Fall Time	$R_G = 5.6\Omega$		30		
Eon	Turn-on Switching Energy	$V_{GE} = 15V \ V_{Bus} = 600V$ $T_j = 125^{\circ}C$		18		m I
$\mathrm{E}_{\mathrm{off}}$	Turn-off Switching Energy	$I_C = 150A$ $R_G = 5.6\Omega$ $T_j = 125^{\circ}C$		8		mJ

Reverse diode ratings and characteristics

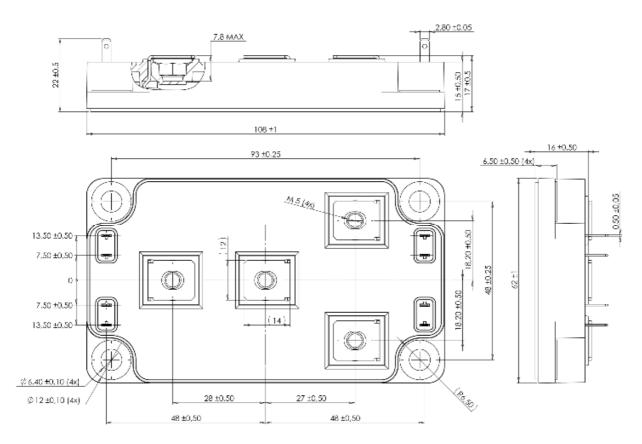
Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
V_{RRM}	Maximum Peak Repetitive Reverse Voltage			1200			V
ī	Maximum Davarga Laglaga Current	V -1200V	$T_j = 25$ °C			350	4
I_{RM}	Maximum Reverse Leakage Current	$V_{R}=1200V$	$T_j = 125$ °C			600	μA
I_{F}	DC Forward Current		$Tc = 85^{\circ}C$		150		A
$V_{\rm F}$	Diode Forward Voltage	$I_F = 150A$	$T_j = 25$ °C		2.1		V
VF			$T_j = 125$ °C		1.9		
4	D. Time		$T_j = 25$ °C		120		
t _{rr}	Reverse Recovery Time	$I_F = 150A$	$T_j = 125$ °C		210		ns
0	Reverse Recovery Charge	$V_{R} = 600V$	$T_j = 25$ °C		11		C
Q_{rr}	Reverse Recovery Charge	$di/dt = 3600A/\mu s$	$T_{j} = 125^{\circ}C$		28		μС
E_{r}	Reverse recovery Energy		$T_j = 25$ °C		3.6		mJ
\mathbf{L}_{I}	Reverse recovery Energy		$T_j = 125$ °C		9		1113



Thermal and package characteristics

Symbol	Characteristic			Min	Typ	Max	Unit
R_{thJC}	Junction to Case Thermal Resistance IGBT Diode		IGBT			0.13	°C/W
T _{th} JC			Diode			0.24	C/ VV
V_{ISOL}	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000			V
$T_{\rm J}$	Operating junction temperature range Storage Temperature Range			-40		150	°C
T_{STG}				-40		125	
T_{C}	Operating Case Temperature			-40		100	
Torque	Mounting torque	To heatsink	M6	3		5	N.m
		For terminals	M5	2		3.5	11.111
Wt	Package Weight					300	g

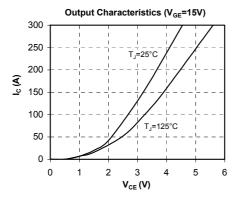
SP6 Package outline (dimensions in mm)

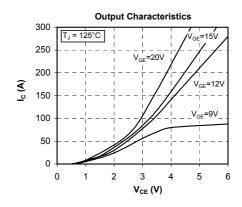


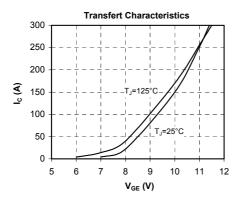
See application note APT0601 - Mounting Instructions for SP6 Power Modules on www.microsemi.com

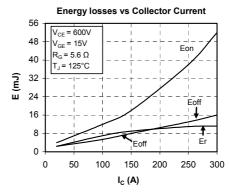


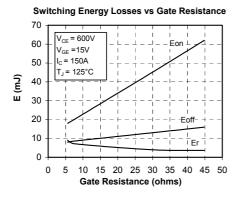
Typical Performance Curve

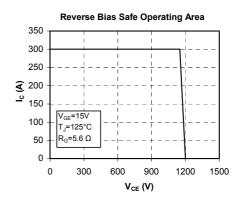


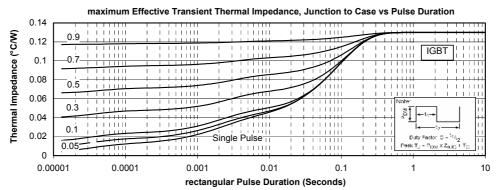




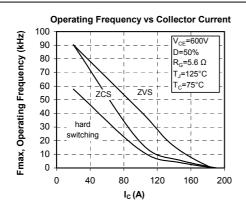


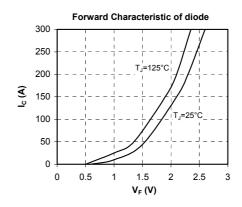


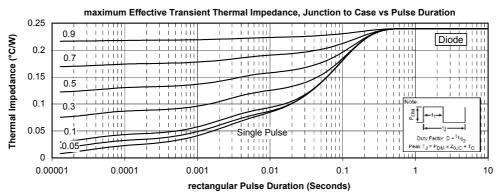














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